NSN 5961-01-301-4430

Unitized Semiconductor Devices - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-301-4430 **Inclosure Material:** Metal **Overall Length:** 1.439 inches **Overall Height:** 0.350 inches **Overall Width:** 1.050 inches **End Application:** Alq-135b **Mounting Facility Quantity:** Joint Electronic Device Engineering Council/jedec/case Outline Designation: **Electrode Internally-electrically Connected To Case: Component Name And Quantity:** 2 semiconductor device diode **Mounting Method:** Unthreaded hole **Semiconductor Material:** Silicon all semiconductor device diode **Voltage Rating In Volts Per Characteristic:** 45.0 working peak reverse voltage all semiconductor device diode and 45.0 reverse voltage, instantaneous all semiconductor device diode **Current Rating Per Characteristic:** 30.00 amperes forward current, average absolute all semiconductor device diode **Maximum Operating Tempurature Per Measurement Point:** 175.0 degrees celsius junction **Test Data Document:** 26916-019-006008 drawing (this is the basic governing drawing, such as a contractor drawing, original equipment manufacturer drawing, etc.; excludes any specification, standard or other document that may be referenced in a basic governing drawing) **Terminal Type And Quantity:** 2 pin and 1 case Shelf Life: N/a **Unit Of Measure: Demilitarization:**

Yes - demil/mli Fiig:

A110a0